

Silicon PNP Darlington Transistor

MJ2500

Power Linear and Switching

60V / 10A

DATASHEET

from

www.web-bcs.com

OEM –SGS Ates

Source: SGS Ates Databook 1977

EPITAXIAL-BASE NPN/PNP

MJ 2500
MJ 2501
MJ 3000
MJ 3001

PRELIMINARY DATA

COMPLEMENTARY POWER DARLINGTONS

The MJ 2500, MJ 2501, MJ 3000 and MJ 3001 are silicon epitaxial-base transistors in monolithic Darlington configuration and are mounted in Jedec TO-3 metal case. They are intended for use in power linear and switching applications.

The PNP types are the MJ 2500 and MJ 2501 and the ir complementary NPN types are the MJ 3000 and MJ 3001 respectively.

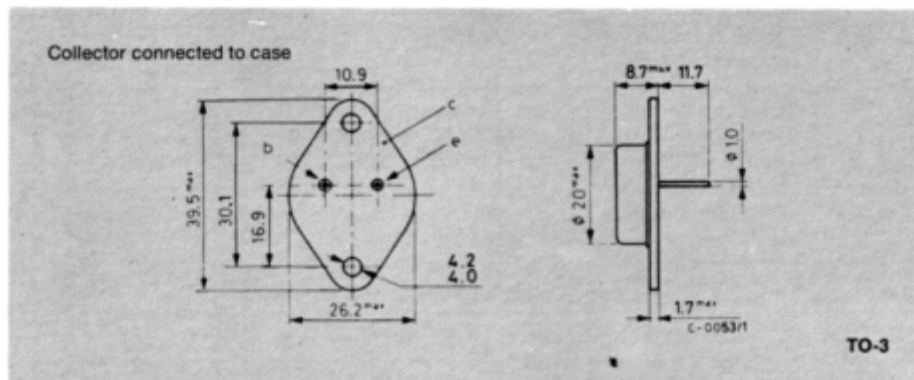
ABSOLUTE MAXIMUM RATINGS

	PNP*	MJ2500	MJ2501
		MJ3000	MJ3001
V_{CBO}	Collector-base voltage ($I_E = 0$)	60V	80V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	60V	80V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5V	
I_C	Collector current	10A	
I_B	Base current	0.2A	
P_{tot}	Total power dissipation at $T_{case} \leq 25\text{ }^\circ\text{C}$	150W	
T_{stg}	Storage temperature	-65 to 200 °C	
T_J	Junction temperature	200 °C	

* For PNP types voltage and current values are negative

MECHANICAL DATA

Dimensions in mm





THERMAL DATA

$R_{th \text{ j-case}}$	Thermal resistance junction-case	max	1.17	°C/W
-------------------------	----------------------------------	-----	------	------

ELECTRICAL CHARACTERISTICS ° ($T_{case} = 25 \text{ °C}$ unless otherwise specified)

Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CER} Collector cutoff current ($R_{BE} = 1k\Omega$)	for MJ2500 and MJ3000 $V_{CE} = 60 \text{ V}$			1	mA
	for MJ2501 and MJ3001 $V_{CE} = 80 \text{ V}$			1	mA
	for MJ2500 and MJ3000 $V_{CE} = 60 \text{ V}$			5	mA
	for MJ2501 and MJ3001 $V_{CE} = 80 \text{ V}$			5	mA
I_{CEO} Collector cutoff current ($I_B = 0$)	for MJ2500 and MJ3000 $V_{CE} = 30 \text{ V}$			1	mA
	for MJ2501 and MJ3001 $V_{CE} = 40 \text{ V}$			1	mA
I_{EBO} Emitter cutoff current ($I_C = 0$)	$V_{EB} = 5 \text{ V}$			2	mA
$V_{CEO(sus)}$ * Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 100\text{mA}$ for MJ2500 and MJ3000 for MJ2501 and MJ3001	60			V
		80			V
$V_{CE(sat)}$ * Collector-emitter saturation voltage	$I_C = 5 \text{ A}$ $I_B = 20\text{mA}$			2	V
	$I_C = 10 \text{ A}$ $I_B = 50\text{mA}$			4	V
V_{BE} * Base-emitter voltage	$I_C = 5 \text{ A}$ $V_{CE} = 3 \text{ V}$			3	V
h_{FE} * DC current gain	$I_C = 5 \text{ A}$ $V_{CE} = 3 \text{ V}$	1000			—

* Pulsed: pulse duration = 300 μs , duty cycle = 1.5%

° For PNP types current and voltage values are negative